

MU320

Merging Unit

Analog and digital, fast and accurate:

Fully-integrated Merging Unit for Process Bus Applications

MU320 is an IEC 61850-9-2LE sampled value interface with conventional current and voltage transformers, integrating GOOSE control for switchgear

Intelligent technologies have brought many benefits in the field of transmission and distribution networks. Digital technology at the station bus level is currently widely spread, to provide a cost effective system to meet the increasing demands for higher standards in power automation. The Reason MU320 merging unit goes one step further to complete the digital substation; facilitating the connection of conventional current and voltage transformers to modern substation automation solutions through IEC 61850-9-2LE.

Benefits

Faulty protection rapid replacement: when the protective relay fails its replacement is carried out without panel rewiring.

Reduced CT windings: The Merging Unit enables that several IEDs read from the same current source.

Reduced CT size: Merging Unit has a very low burden.

Eliminates the need for supervision cables: communication is intrinsically supervised.

Increased uptime: protection can receive data from multiple Merging Units.

Less risk of opening CT circuit: signal is transmitted by messages over Ethernet network.

High accuracy Class 0.1 analog card for metering applications panels reducing

drastically costs with trenches and copper cabling, for instance.

Reduced project complexity: by reducing cabling and physical connections.

In the event of communication loss, all main information is signaled via LEDs (Power, In Service, Alarm, Sync, LAN A and LAN B).

Front-end software configuration for standardized SCL file.

POWER SUPPLY

Power supply 100-250 Vdc, 110- 240 Vac	
Operating nominal voltage	100-250 V dc, 110- 240 V ac
Frequency	50/60 Hz ± 3Hz
Operating voltage range	80 - 275 V dc, 88 - 264 V ac
Power Consumption	MAX 20 VA
	Typically 14 W
Interruptions	40 ms @ 125 V a.c. / V d.c.
	100 ms @ 250 V a.c. / V d.c.
Connector	3 pin: positive (phase), negative (neutral) and ground

Power supply 24/48 Vdc Operating nominal

voltage	
Frequency	50/60 Hz ± 3Hz
Operating voltage range	18 – 72 Vdc
Power Consumption	45 W @ 700mA
Connector	3 pin: positive (phase), negative (neutral) and ground

24/48 Vdc

OPTICAL IRIG-B INPUT

Signal	IRIG-B004
Wavelength	820 nm
Fiber type	Multimode 62.5 / 125 μm
Connector	ST
	- 24 dBm
Maximum curvature ratio	30 mm
	100 ms @ 250 V a.c. / V d.c.
Connector	3 pin: positive (phase), negative (neutral) and ground



INTERNAL	OSCILLATOR

26-1	±50PPM
rift when not locked	(8.64 seconds/day)

IN SERVICE CONTACT

Description	Dry contact relay, normally closed
Switching Voltage	250 V (AC and DC)
Permissible current continuous	5 A
Maximum voltage	300 (AC and DC)
Making Capacity	15 A, 4 sec
Breaking Capacity	40W Resistive, 25 W/VA L/R = 50
Dropout time	< 5 ms
Burden	~50mA @12V [600mW]
Withstand voltages across open contacts	1000V rms
Permissible short time value for 1s	30A

DIMENSIONS AND WEIGHT

Height	222 mm / 8.7 in (5 U)
Width	222 mm / 8.7 in (½ 19")
Depth	121 mm / 4.7 in
Weight	< 3.5 kg (< 7.72 lb)

ANALOG ACQUISITION

Resolution	16 bits
Acquisition rate	80 and 256 ppc
Attenuation @ 800 Hz	3 dB
Group delay	664µs

BINARY INPUTS			
Nominal Voltage	125 V	250 V	24 / 48 V
Level Low	40 V	75 V	08 V
Level High	85 V	160 V	17 V
Impedance	82 kΩ	160 kΩ	15 kΩ
Burden	< 0.25 W	< 0.5 W	< 0.2 W
Continuous Overload	240 V	340 V	100 V

BINARY OUTPUTS	
Description	Dry contact relay, normally open
Switching Voltage	250 V (AC and DC)
Maximum continuous current	5 A
Maximum voltage	300 (AC and DC)
Making Capacity	15 A, 4 sec
Breaking Capacity	40 W Resistive, 25 W/VA L/R = 50
Operation time / Dropout time	< 5 ms
Burden	Per energized output relay: ~50mA @12V [600mW]
Withstand voltages across open contacts	1000V rms
Permissible short time value for 1s	30A

BINARY OUTPUTS

Description	Uses IGBT technology
Rated voltage	250 V
Breaking Capacity	10A @ 250Vac with L/R= 40 ms
Make & Break, dc resistive	1368 W
Operation time	< 0.2ms
Reset time	< 8ms
Max number of operation	≥10000

OPTICAL ETHERNET PORTS	
Interface	100BASE-FX
Bitrate	100 Mbps
Wavelength	1300 nm
Connector	LC
Fiber type	multimode 62.5 / 125 μm
Emission power	-20 dBm
Sensitivity	-32 dBm
Maximum applicable power	-14 dBm

VOLTAGE INPUTS		
Nominal Voltage (Vn)	115 V	
Nominal frequency	50/60Hz	
Voltage range	0.02 230 V	
Accuracy	± 0.1 % F.S.	
Impedance	> 210 k Ω	
Burden Vn	< 0.1VA	
Continuous overload	240 V	
Maximum overload (1 s)	460 V (4 x Vn)	
Bandwidth	3 k Hz	

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Characteristic	Standard Input	Standard Input	High accuracy Inputs
Nominal Current (In)	5 A	1 A	1 and 5 A
Nominal frequency	50/60Hz	50/60Hz	50/60Hz
Current range (rms)	0.25 200A	0.05 40A	0.005 10 A
Accuracy	± 0.1 % F.S.	± 0.1 % F.S.	Class 0.1 (IEC 61869-2) 0,05 A to 10 A better than 0,1% of the measurement ± 1mA
Impedance	3 m Ω	15 m Ω	15 mΩ
Burden In	50 m VA	< 0.02 VA	< 0.02 VA
Continuous overload	20A (4 x In)	4A (4 x In)	10 A
AC current thermal withstand 1 s (Ith rms)	320A (64 x In)	100A (100x In)	100 A
AC current thermal withstand 10 s (Ith rms)	100A (20 x In)	30A (30 x In)	30 A
Insulation	> 3.5 kV	> 3.5 kV	>3,5 kV
Bandwidth	1 k Hz	1 k Hz	1 k Hz

TYPE TEST				
EMC tests were performed according to IEC 60255-26 referring to the following standards				
IEC 61000-4-2:2008	6kV contact / 8KV air			
IEC 61000-4-3:2006	10 V/m			
IEC 61000-4-4:2012	2 KV @ 5KHz			
IEC 61000-4-5:2005	Differential mode: 2KV Common mode: 1KV			
IEC 61000-4-6:2008	10V			
IEC 61000-4-8:2009	30A/m continuos - 300A/m @ 1s			
IEC 61000-4- 11:2004 IEC 61000-4- 29:2000	- A.C. and d.c. voltage dips Test level: 0% residual voltage Duration time a.c.: 1 cycle d.c.: 16,6ms - Test level: 40% residual voltage Duration time a.c.: 12 cycles d.c.: 200ms - Test level: 70% residual voltage Duration time a.c.: 30 cycles d.c.:500ms A.C. and d.c. voltage interruptions - Test level: 0% residual voltage Duration time a.c.: 300 cycles d.c.: 500 cycles d.c.: 500 cycles d.c.: 500 cycles			
IEC 61000-4- 16:1998	Differential mode: 100V r.m.s. Common mode: 300V r.m.s. Freq: 16,7 Hz, 50 Hz or 60 Hz			
IEC 61000-4- 17:1999	Test level: 15 % of rated d.c. value Test frequency: 120Hz, sinusoidal waveform			
IEC 61000-4- 18:2006	Voltage oscillation frequency: 1MHz Differential mode: 1kV peak voltage; Common mode 2,5kV peak voltage			
Gradual Startup	Shut-down ramp: 60s Power off: 5m Start-up ramp: 60s			
CISPR11:2009	Radiated emission Limits: 30 to 230MHz - 50dB(µV/m) quasi peak at 3m			

CISPR22:2008	Limit 1 to avera 3 m Limit maxi 125N Cond Limit 0.15 quas 0.5 t	Radiated emission Limits: 1 to 2GHz - 56dB(µV/m) average; 76dB(µV/m) peak at 3m Limits defined considering the maximum internal frequency of 125MHz Conducted emission Limits: 0.15 to 0.50MHZ - 79dB(µV) quasi peak; 66dB(µV) average 0.5 to 30MHz - 73dB(µV) quasi peak; 60dB(µV) average		
Safety tests				
Safety	IEC 6	IEC 60255-27		
IEC 60255-5	Diele	Inpulse - 5KV Dielectric withstand - 3,3KVDC Insulation > 100M Ω		
Environmental tests				
IEC 60068-2-1	-40°	C, 16 hours (Cold)		
IEC 60068-2-2	+85°	+85°C, 16 hours (Dry heat)		
IEC 60068-2-30		95% no condensation, 55°C (Damp heat)		
IEC 60068-2-14		-40°C to 85°C / 9 hours / 2 cycles (Change of temperature)		
IEC 60255-21-1	Class	Class 2 (Vibration)		
IEC 60255-21-2	Class	Class 1 (Shock)		
OPTICAL ETHERNET	PORT	S		
Optical Ethernet por	ts spec	ifications		
Operating temperature range		-40 °C (-40 °F) +55°C (+131°F)		
Tested as per IEC 60068-2-1:2013		-40°C (-40°F)		
Tested as per		+85°C (+185°F)		

IP54

IP20

 $0 \dots 95$ %, noncondensing

IP10 (for the rear due to live

GE Grid Solutions

Reason Product Line +55 48 21080300 www.gegridsolutions.com 230 to 1000MHz - 57dB(μV/m)

quasi peak at 3m

IEC 60068-2-2:2013 Relative humidity

panel Rear and sides

Enclosure Protection IEC 60529 Front flush mounted with

Product safety protection